

## LMP7707/LMP7708/LMP7709 Precision, CMOS Input, RRIO, Wide Supply Range Decompensated Amplifiers

Check for Samples: [LMP7707](#), [LMP7708](#), [LMP7709](#)

### FEATURES

- Unless otherwise noted, typical values at  $V_S = 5V$ .
- Input offset voltage (LMP7707)  $\pm 200 \mu V$  (max)
- Input offset voltage (LMP7708/LMP7709)  $\pm 220 \mu V$  (max)
- Input bias current  $\pm 200 fA$
- Input voltage noise  $9 nV/\sqrt{Hz}$
- CMRR 130 dB
- Open loop gain 130 dB
- Temperature range  $-40^\circ C$  to  $125^\circ C$
- Gain bandwidth product ( $A_V = 10$ ) 14 MHz
- Stable at a gain of 10 or higher

- Supply current (LMP7707) 715  $\mu A$
- Supply current (LMP7708) 1.5 mA
- Supply current (LMP7709) 2.9 mA
- Supply voltage range 2.7V to 12V
- Rail-to-rail input and output

### APPLICATIONS

- High impedance sensor interface
- Battery powered instrumentation
- High gain amplifiers
- DAC buffer
- Instrumentation amplifier
- Active filters

### DESCRIPTION

The LMP7707/LMP7708/LMP7709 devices are single, dual, and quad low offset voltage, rail-to-rail input and output precision amplifiers which each have a CMOS input stage and a wide supply voltage range. The LMP7707/LMP7708/LMP7709 are part of the LMP™ precision amplifier family and are ideal for sensor interface and other instrumentation applications. These decompensated amplifiers are stable at a gain of 6 and higher.

The guaranteed low offset voltage of less than  $\pm 200 \mu V$  along with the guaranteed low input bias current of less than  $\pm 1 pA$  make the LMP7707/LMP7708/LMP7709 ideal for precision applications. The LMP7707/LMP7708/LMP7709 are built utilizing VIP50 technology, which allows the combination of a CMOS input stage and a supply voltage range of 12V with rail-to-rail common mode voltage capability. The LMP7707/LMP7708/LMP7709 are the perfect choice in many applications where conventional CMOS parts cannot operate due to the voltage conditions.

The unique design of the rail-to-rail input stage of each of the LMP7707/LMP7708/LMP7709 significantly reduces the CMRR glitch commonly associated with rail-to-rail input amplifiers. Both sides of the complimentary input stage have been trimmed, thereby reducing the difference between the NMOS and PMOS offsets. The output swings within 40 mV of either rail to maximize the signal dynamic range in applications requiring low supply voltage.

The LMP7707 is offered in the space saving 5-Pin SOT23 and 8-pin SOIC package, the LMP7708 is offered in the 8-Pin MSOP and 8-pin SOIC package and the quad LMP7709 is offered in the 14-Pin TSSOP and the 14-pin SOIC package. These small packages are ideal solutions for area constrained PC boards and portable electronics.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

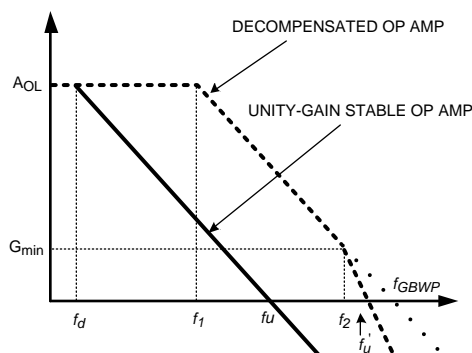
LMP is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2007–2008, Texas Instruments Incorporated

## Open Loop Frequency Response



**Figure 1. Increased Bandwidth for Same Supply Current at  $A_V > 10$**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings <sup>(1)</sup>

ESD Tolerance <sup>(2)</sup>	
Human Body Model	2000V
Machine Model	200V
Charge Device Model	1000V
$V_{IN}$ Differential	$\pm 300$ mV
Supply Voltage ( $V_S = V^+ - V^-$ )	13.2V
Voltage at Input/Output Pins	$V^+ + 0.3V$ to $V^- - 0.3V$
Input Current	10 mA
Storage Temperature Range	$-65^\circ\text{C}$ to $+150^\circ\text{C}$
Junction Temperature <sup>(3)</sup>	$+150^\circ\text{C}$
Soldering Information	
Infrared or Convection (20 sec)	$235^\circ\text{C}$
Wave Soldering Lead Temp. (10 sec)	$260^\circ\text{C}$

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics Tables.
- (2) Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).
- (3) The maximum power dissipation is a function of  $T_{J(MAX)}$ ,  $\theta_{JA}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly onto a PC board.

## Operating Ratings <sup>(1)</sup>

Temperature Range <sup>(2)</sup>	$-40^\circ\text{C}$ to $+125^\circ\text{C}$
Supply Voltage ( $V_S = V^+ - V^-$ )	2.7V to 12V
Package Thermal Resistance ( $\theta_{JA}$ ) <sup>(2)</sup>	
5-Pin SOT23	$265^\circ\text{C/W}$
8-Pin SOIC	$190^\circ\text{C/W}$
8-Pin MSOP	$235^\circ\text{C/W}$
14-Pin TSSOP	$122^\circ\text{C/W}$

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics Tables.
- (2) The maximum power dissipation is a function of  $T_{J(MAX)}$ ,  $\theta_{JA}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly onto a PC board.

**Operating Ratings <sup>(1)</sup> (continued)**

14-Pin SOIC	145°C/W
-------------	---------

### 3V Electrical Characteristics <sup>(1)</sup>

Unless otherwise specified, all limits are guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V^+ = 3\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = V^+/2$ , and  $R_L > 10\text{ k}\Omega$  to  $V^+/2$ .

**Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
$V_{\text{OS}}$	Input Offset Voltage	LMP7707		$\pm 37$	$\pm 200$ <b><math>\pm 500</math></b>	$\mu\text{V}$
		LMP7708/LMP7709		$\pm 56$	$\pm 220$ <b><math>\pm 520</math></b>	
$\text{TCV}_{\text{OS}}$	Input Offset Voltage Drift <sup>(4)</sup>			$\pm 1$	<b><math>\pm 5</math></b>	$\mu\text{V}/^\circ\text{C}$
$I_{\text{B}}$	Input Bias Current <sup>(4) (5)</sup>			$\pm 0.2$	$\pm 1$	$\text{pA}$
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$			$\pm 50$	
		$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$			$\pm 400$	
$I_{\text{OS}}$	Input Offset Current			40		$\text{fA}$
CMRR	Common Mode Rejection Ratio	$0\text{V} \leq V_{\text{CM}} \leq 3\text{V}$ LMP7707	86 <b>80</b>	130		$\text{dB}$
		$0\text{V} \leq V_{\text{CM}} \leq 3\text{V}$ LMP7708/LMP7709	84 <b>78</b>	130		
PSRR	Power Supply Rejection Ratio	$2.7\text{V} \leq V^+ \leq 12\text{V}$ , $V_{\text{O}} = V^+/2$	86 <b>82</b>	98		$\text{dB}$
CMVR	Input Common-Mode Voltage Range	CMRR $\geq 80\text{ dB}$	$-0.2$		3.2	$\text{V}$
		CMRR $\geq 77\text{ dB}$	<b><math>-0.2</math></b>		<b>3.2</b>	
$A_{\text{VOL}}$	Open Loop Voltage Gain	$R_L = 2\text{ k}\Omega$ (LMP7707) $V_{\text{O}} = 0.3\text{V to } 2.7\text{V}$	100 <b>96</b>	114		$\text{dB}$
		$R_L = 2\text{ k}\Omega$ (LMP7708/LMP7709) $V_{\text{O}} = 0.3\text{V to } 2.7\text{V}$	100 <b>94</b>	114		
		$R_L = 10\text{ k}\Omega$ $V_{\text{O}} = 0.2\text{V to } 2.8\text{V}$	100 <b>96</b>	124		
$V_{\text{O}}$	Output Swing High	$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7707		40	80 <b>120</b>	$\text{mV}$ from $V^+$
		$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		40	80 <b>150</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7707		30	40 <b>60</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		35	50 <b>100</b>	
	Output Swing Low	$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7707		40	60 <b>80</b>	$\text{mV}$
		$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		45	100 <b>170</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7707		20	40 <b>50</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		20	50 <b>90</b>	

- (1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.
- (2) Limits are 100% production tested at  $25^\circ\text{C}$ . Limits over the operating temperature range are guaranteed through correlations using the Statistical Quality Control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- (4) This parameter is guaranteed by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.

### 3V Electrical Characteristics <sup>(1)</sup> (continued)

Unless otherwise specified, all limits are guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V^+ = 3\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{\text{CM}} = V^+/2$ , and  $R_L > 10\text{ k}\Omega$  to  $V^+/2$ .

**Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
$I_O$	Output Short Circuit Current (6) (7)	Sourcing $V_O = V^+/2$ $V_{\text{IN}} = 100\text{ mV}$	25 <b>15</b>	42		mA
		Sinking $V_O = V^+/2$ $V_{\text{IN}} = -100\text{ mV}$ (LMP7707)	25 <b>20</b>	42		
		Sinking $V_O = V^+/2$ $V_{\text{IN}} = -100\text{ mV}$ (LMP7708/LMP7709)	25 <b>15</b>	42		
$I_S$	Supply Current	LMP7707		0.670	1.0 <b>1.2</b>	mA
		LMP7708		1.4	1.8 <b>2.1</b>	
		LMP7709		2.9	3.5 <b>4.5</b>	
SR	Slew Rate <sup>(8)</sup>	$V_O = 2\text{ V}_{\text{PP}}$ , 10% to 90%		5.1		V/ $\mu\text{s}$
GBWP	Gain Bandwidth Product	$A_V = 10$		13		MHz
THD+N	Total Harmonic Distortion + Noise	$f = 1\text{ kHz}$ , $A_V = 10$ , $V_O = 2.5\text{V}$ , $R_L = 10\text{ k}\Omega$		0.024		%
$e_n$	Input-Referred Voltage Noise	$f = 1\text{ kHz}$		9		nV/ $\sqrt{\text{Hz}}$
$i_n$	Input-Referred Current Noise	$f = 100\text{ kHz}$		1		fA/ $\sqrt{\text{Hz}}$

(6) The maximum power dissipation is a function of  $T_{\text{J(MAX)}}$ ,  $\theta_{\text{JA}}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{\text{J(MAX)}} - T_A) / \theta_{\text{JA}}$ . All numbers apply for packages soldered directly onto a PC board.

(7) The short circuit test is a momentary test.

(8) The number specified is the slower of positive and negative slew rates.

## 5V Electrical Characteristics <sup>(1)</sup>

Unless otherwise specified, all limits are guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V^+ = 5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = V^+/2$ , and  $R_L > 10\text{ k}\Omega$  to  $V^+/2$ .

**Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
$V_{OS}$	Input Offset Voltage	LMP7707		$\pm 37$	$\pm 200$ <b><math>\pm 500</math></b>	$\mu\text{V}$
		LMP7708/LMP7709		$\pm 32$	$\pm 220$ <b><math>\pm 520</math></b>	
$TCV_{OS}$	Input Offset Voltage Drift <sup>(4)</sup>			$\pm 1$	<b><math>\pm 5</math></b>	$\mu\text{V}/^\circ\text{C}$
$I_B$	Input Bias Current <sup>(4) (5)</sup>			$\pm 0.2$	$\pm 1$	$\text{pA}$
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$			$\pm 50$	
		$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$			$\pm 400$	
$I_{OS}$	Input Offset Current			40		$\text{fA}$
CMRR	Common Mode Rejection Ratio	$0\text{V} \leq V_{CM} \leq 5\text{V}$ LMP7707	88 <b>83</b>	130		$\text{dB}$
		$0\text{V} \leq V_{CM} \leq 5\text{V}$ LMP7708/LMP7709	86 <b>81</b>	130		
PSRR	Power Supply Rejection Ratio	$2.7\text{V} \leq V^+ \leq 12\text{V}$ , $V_O = V^+/2$	86 <b>82</b>	100		$\text{dB}$
CMVR	Input Common-Mode Voltage Range	CMRR $\geq 80\text{ dB}$	$-0.2$		5.2	$\text{V}$
		CMRR $\geq 78\text{ dB}$	<b><math>-0.2</math></b>		<b>5.2</b>	
$A_{VOL}$	Open Loop Voltage Gain	$R_L = 2\text{ k}\Omega$ (LMP7707) $V_O = 0.3\text{V to } 4.7\text{V}$	100 <b>96</b>	119		$\text{dB}$
		$R_L = 2\text{ k}\Omega$ (LMP7708/LMP7709) $V_O = 0.3\text{V to } 4.7\text{V}$	100 <b>94</b>	119		
		$R_L = 10\text{ k}\Omega$ $V_O = 0.2\text{V to } 4.8\text{V}$	100 <b>96</b>	130		
$V_O$	Output Swing High	$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7707		60	110 <b>130</b>	$\text{mV}$ from $V^+$
		$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		60	120 <b>200</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7707		40	50 <b>70</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		40	60 <b>120</b>	
	Output Swing Low	$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7707		50	80 <b>90</b>	$\text{mV}$
		$R_L = 2\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		50	120 <b>190</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7707		30	40 <b>50</b>	
		$R_L = 10\text{ k}\Omega$ to $V^+/2$ LMP7708/LMP7709		30	50 <b>100</b>	

- (1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.
- (2) Limits are 100% production tested at  $25^\circ\text{C}$ . Limits over the operating temperature range are guaranteed through correlations using the Statistical Quality Control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- (4) This parameter is guaranteed by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.

## 5V Electrical Characteristics <sup>(1)</sup> (continued)

Unless otherwise specified, all limits are guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V^+ = 5\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = V^+/2$ , and  $R_L > 10\text{ k}\Omega$  to  $V^+/2$ .

**Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
$I_O$	Output Short Circuit Current (6) (7)	Sourcing $V_O = V^+/2$ $V_{IN} = 100\text{ mV}$ (LMP7707)	40 <b>28</b>	66		mA
		Sourcing $V_O = V^+/2$ $V_{IN} = 100\text{ mV}$ (LMP7708/LMP7709)	38 <b>25</b>	66		
		Sinking $V_O = V^+/2$ $V_{IN} = -100\text{ mV}$ (LMP7707)	40 <b>28</b>	76		
		Sinking $V_O = V^+/2$ $V_{IN} = -100\text{ mV}$ (LMP7708/LMP7709)	40 <b>23</b>	76		
$I_S$	Supply Current	LMP7707		0.715	1.0 <b>1.2</b>	mA
		LMP7708		1.5	1.9 <b>2.2</b>	
		LMP7709		2.9	3.7 <b>4.6</b>	
SR	Slew Rate <sup>(8)</sup>	$V_O = 4\text{ V}_{PP}$ , 10% to 90%		5.6		V/ $\mu\text{s}$
GBWP	Gain Bandwidth Product	$A_V = 10$		14		MHz
THD+N	Total Harmonic Distortion + Noise	$f = 1\text{ kHz}$ , $A_V = 10$ , $V_O = 4.5\text{V}$ , $R_L = 10\text{ k}\Omega$		0.024		%
$e_n$	Input-Referred Voltage Noise	$f = 1\text{ kHz}$		9		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input-Referred Current Noise	$f = 100\text{ kHz}$		1		$\text{fA}/\sqrt{\text{Hz}}$

(6) The maximum power dissipation is a function of  $T_{J(\text{MAX})}$ ,  $\theta_{JA}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(\text{MAX})} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly onto a PC board.

(7) The short circuit test is a momentary test.

(8) The number specified is the slower of positive and negative slew rates.

**±5V Electrical Characteristics** <sup>(1)</sup>

Unless otherwise specified, all limits are guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V^+ = 5\text{V}$ ,  $V^- = -5\text{V}$ ,  $V_{CM} = 0\text{V}$ , and  $R_L > 10\text{ k}\Omega$  to  $0\text{V}$ .

**Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
$V_{OS}$	Input Offset Voltage	LMP7707		$\pm 37$	$\pm 200$ <b><math>\pm 500</math></b>	$\mu\text{V}$
		LMP7708/LMP7709		$\pm 37$	$\pm 220$ <b><math>\pm 520</math></b>	
$TCV_{OS}$	Input Offset Voltage Drift <sup>(4)</sup>			$\pm 1$	<b><math>\pm 5</math></b>	$\mu\text{V}/^\circ\text{C}$
$I_B$	Input Bias Current <sup>(4) (5)</sup>			$\pm 0.2$	1	$\text{pA}$
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$			$\pm 50$	
		$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$			$\pm 400$	
$I_{OS}$	Input Offset Current			40		$\text{fA}$
CMRR	Common Mode Rejection Ratio	$-5\text{V} \leq V_{CM} \leq 5\text{V}$ LMP7707	92 <b>88</b>	138		$\text{dB}$
		$-5\text{V} \leq V_{CM} \leq 5\text{V}$ LMP7708/LMP7709	90 <b>86</b>	138		
PSRR	Power Supply Rejection Ratio	$2.7\text{V} \leq V^+ \leq 12\text{V}$ , $V^- = 0\text{V}$ , $V_O = V^+/2$	86 <b>82</b>	98		$\text{dB}$
CMVR	Input Common-Mode Voltage Range	CMRR $\geq 80\text{ dB}$	-5.2		5.2	$\text{V}$
		CMRR $\geq 78\text{ dB}$	<b>-5.2</b>		<b>5.2</b>	
$A_{VOL}$	Open Loop Voltage Gain	$R_L = 2\text{ k}\Omega$ (LMP7707) $V_O = -4.7\text{V}$ to $4.7\text{V}$	100 <b>98</b>	121		$\text{dB}$
		$R_L = 2\text{ k}\Omega$ (LMP7708/LMP7709) $V_O = -4.7\text{V}$ to $4.7\text{V}$	100 <b>94</b>	121		
		$R_L = 10\text{ k}\Omega$ (LMP7707) $V_O = -4.8\text{V}$ to $4.8\text{V}$	100 <b>98</b>	134		
		$R_L = 10\text{ k}\Omega$ (LMP7708/LMP7709) $V_O = -4.8\text{V}$ to $4.8\text{V}$	100 <b>97</b>	134		
$V_O$	Output Swing High	$R_L = 2\text{ k}\Omega$ to $0\text{V}$ LMP7707		90	150 <b>170</b>	$\text{mV}$ from $V^+$
		$R_L = 2\text{ k}\Omega$ to $0\text{V}$ LMP7708/LMP7709		90	180 <b>290</b>	
		$R_L = 10\text{ k}\Omega$ to $0\text{V}$ LMP7707		40	80 <b>100</b>	
		$R_L = 10\text{ k}\Omega$ to $0\text{V}$ LMP7708/LMP7709		40	80 <b>150</b>	
	Output Swing Low	$R_L = 2\text{ k}\Omega$ to $0\text{V}$ LMP7707		90	130 <b>150</b>	$\text{mV}$ from $V^-$
		$R_L = 2\text{ k}\Omega$ to $0\text{V}$ LMP7708/LMP7709		90	180 <b>290</b>	
		$R_L = 10\text{ k}\Omega$ to $0\text{V}$ LMP7707		40	50 <b>60</b>	
		$R_L = 10\text{ k}\Omega$ to $0\text{V}$ LMP7708/LMP7709		40	60 <b>110</b>	

- (1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.
- (2) Limits are 100% production tested at  $25^\circ\text{C}$ . Limits over the operating temperature range are guaranteed through correlations using the Statistical Quality Control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- (4) This parameter is guaranteed by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.



## ±5V Electrical Characteristics <sup>(1)</sup> (continued)

Unless otherwise specified, all limits are guaranteed for  $T_A = 25^\circ\text{C}$ ,  $V^+ = 5\text{V}$ ,  $V^- = -5\text{V}$ ,  $V_{CM} = 0\text{V}$ , and  $R_L > 10\text{ k}\Omega$  to  $0\text{V}$ .

**Boldface** limits apply at the temperature extremes.

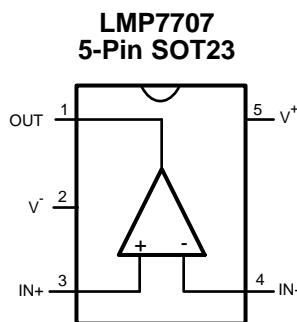
Symbol	Parameter	Conditions	Min (2)	Typ (3)	Max (2)	Units
$I_O$	Output Short Circuit Current (6) (7)	Sourcing $V_O = 0\text{V}$ $V_{IN} = 100\text{ mV}$ (LMP7707)	50 <b>35</b>	86		mA
		Sourcing $V_O = 0\text{V}$ $V_{IN} = 100\text{ mV}$ (LMP7708/LMP7709)	48 <b>33</b>	86		
		Sinking $V_O = 0\text{V}$ $V_{IN} = -100\text{ mV}$	50 <b>35</b>	84		
$I_S$	Supply Current	LMP7707		0.790	1.1 <b>1.3</b>	mA
		LMP7708		1.7	2.1 <b>2.5</b>	
		LMP7709		3.2	4.2 <b>5.0</b>	
SR	Slew Rate <sup>(8)</sup>	$V_O = 9\text{ V}_{PP}$ , 10% to 90%		5.9		V/ $\mu\text{s}$
GBWP	Gain Bandwidth Product	$A_V = 10$		15		MHz
THD+N	Total Harmonic Distortion + Noise	$f = 1\text{ kHz}$ , $A_V = 10$ , $V_O = 9\text{V}$ , $R_L = 10\text{ k}\Omega$		0.024		%
$e_n$	Input-Referred Voltage Noise	$f = 1\text{ kHz}$		9		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$	Input-Referred Current Noise	$f = 100\text{ kHz}$		1		$\text{fA}/\sqrt{\text{Hz}}$

(6) The maximum power dissipation is a function of  $T_{J(\text{MAX})}$ ,  $\theta_{JA}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(\text{MAX})} - T_A) / \theta_{JA}$ . All numbers apply for packages soldered directly onto a PC board.

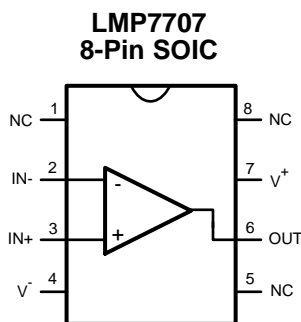
(7) The short circuit test is a momentary test.

(8) The number specified is the slower of positive and negative slew rates.

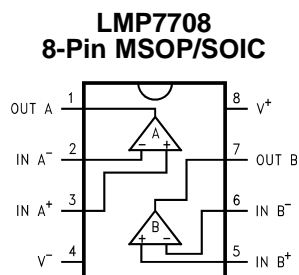
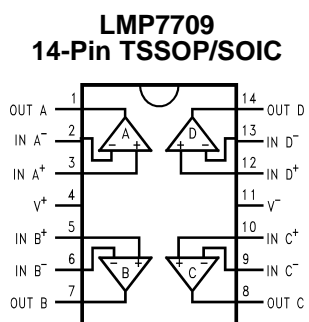
## Connection Diagram



**Figure 2. Top View**

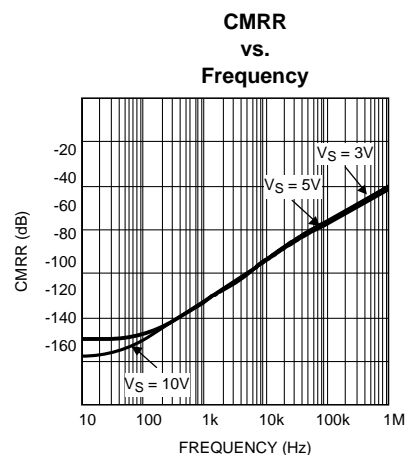
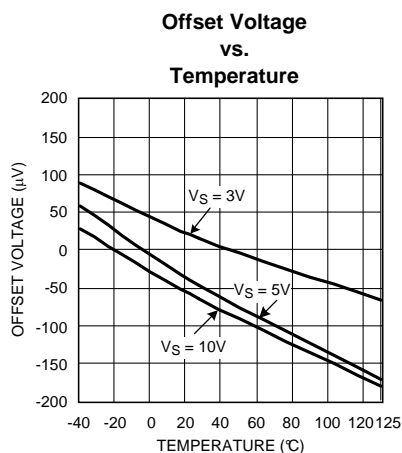
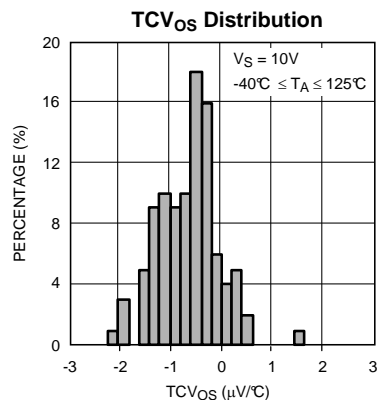
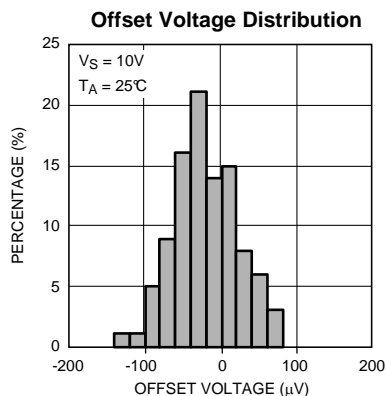
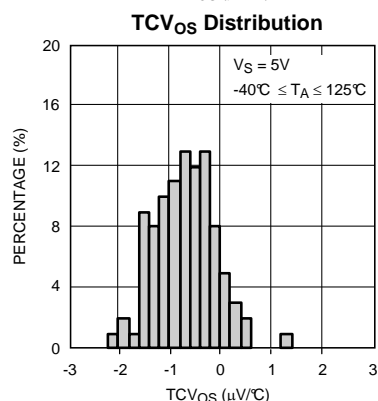
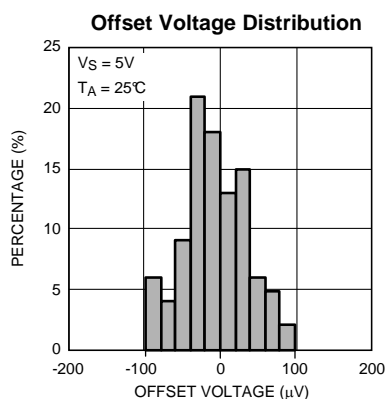
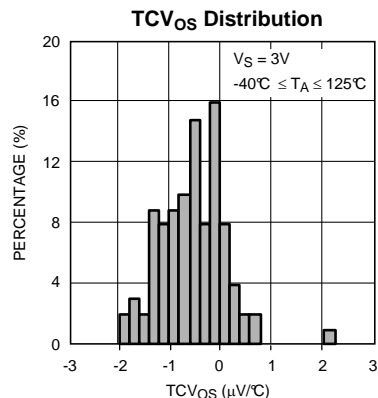
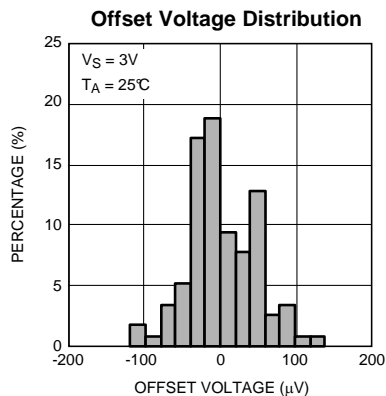


**Figure 3. Top View**

**Figure 4. Top View****Figure 5. Top View**

## Typical Performance Characteristics

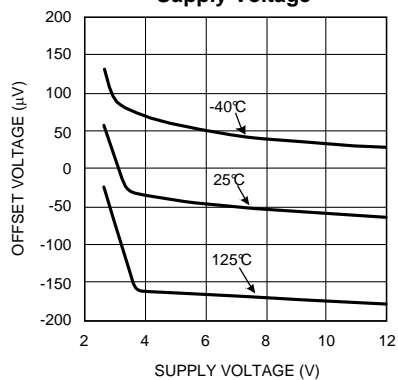
Unless otherwise specified,  $T_A = 25^\circ\text{C}$ ,  $V_{CM} = V_S/2$ ,  $R_L > 10\text{ k}\Omega$  connected to  $(V^+ + V^-)/2$



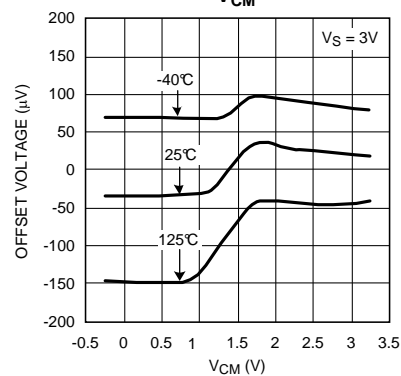
### Typical Performance Characteristics (continued)

Unless otherwise specified,  $T_A = 25^\circ\text{C}$ ,  $V_{CM} = V_S/2$ ,  $R_L > 10\text{ k}\Omega$  connected to  $(V^+ + V^-)/2$

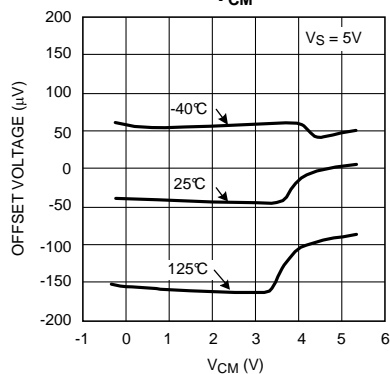
**Offset Voltage  
vs.  
Supply Voltage**



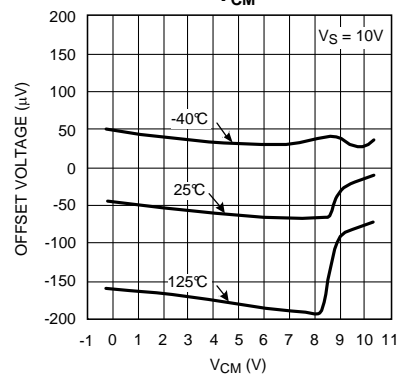
**Offset Voltage  
vs.  
 $V_{CM}$**



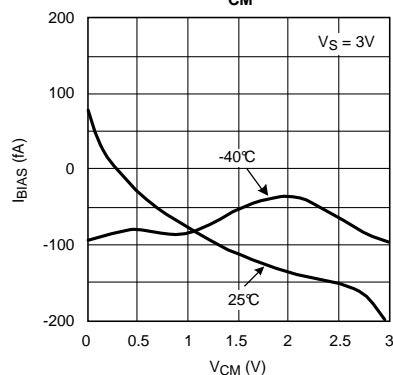
**Offset Voltage  
vs.  
 $V_{CM}$**



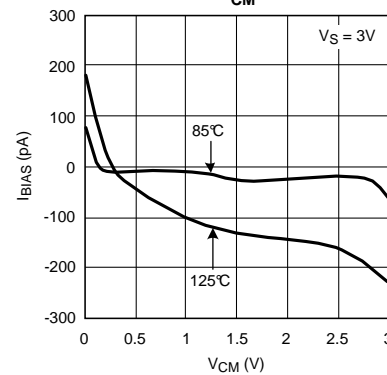
**Offset Voltage  
vs.  
 $V_{CM}$**



**Input Bias Current  
vs.  
 $V_{CM}$**



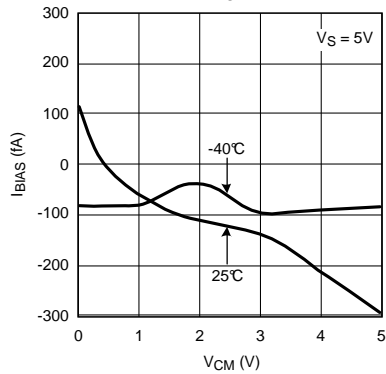
**Input Bias Current  
vs.  
 $V_{CM}$**



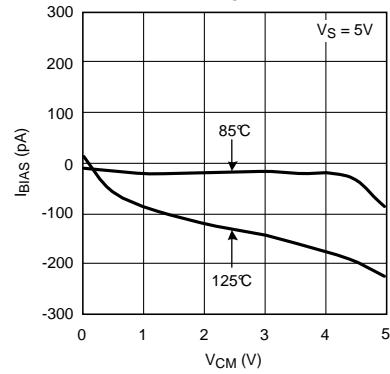
## Typical Performance Characteristics (continued)

Unless otherwise specified,  $T_A = 25^\circ\text{C}$ ,  $V_{CM} = V_S/2$ ,  $R_L > 10\text{ k}\Omega$  connected to  $(V^+ + V^-)/2$

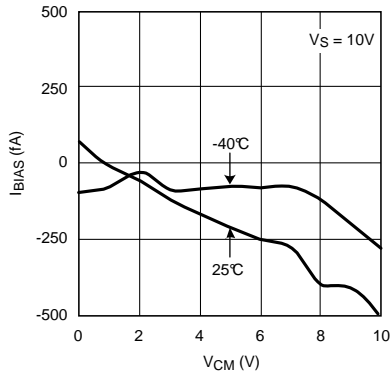
**Input Bias Current  
vs.  
 $V_{CM}$**



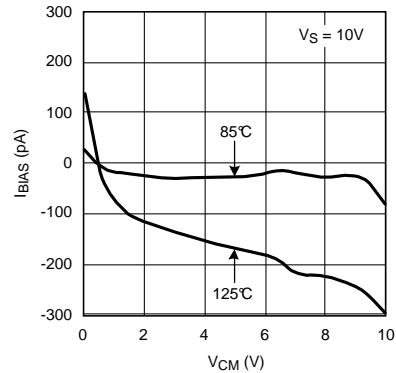
**Input Bias Current  
vs.  
 $V_{CM}$**



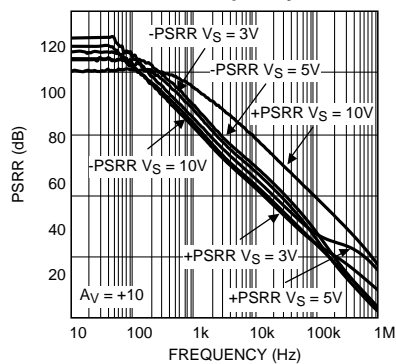
**Input Bias Current  
vs.  
 $V_{CM}$**



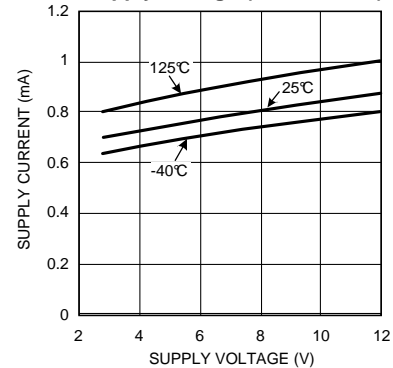
**Input Bias Current  
vs.  
 $V_{CM}$**



**PSRR  
vs.  
Frequency**



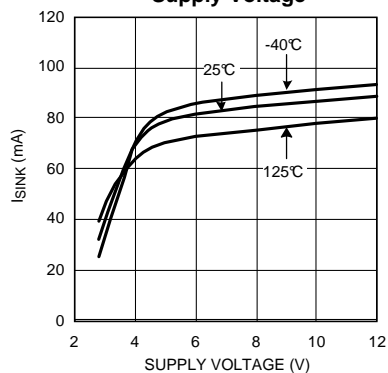
**Supply Current  
vs.  
Supply Voltage (Per Channel)**



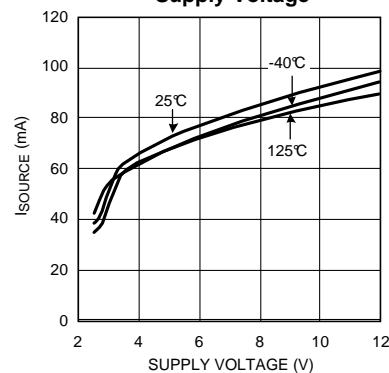
## Typical Performance Characteristics (continued)

Unless otherwise specified,  $T_A = 25^\circ\text{C}$ ,  $V_{CM} = V_S/2$ ,  $R_L > 10\text{ k}\Omega$  connected to  $(V^+ + V^-)/2$

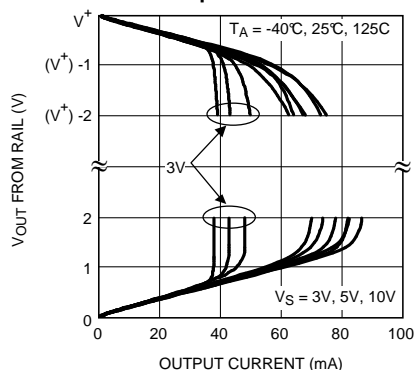
**Sinking Current  
vs.  
Supply Voltage**



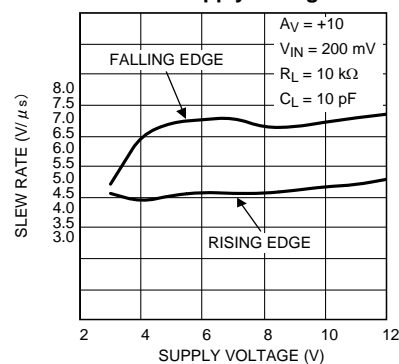
**Sourcing Current  
vs.  
Supply Voltage**



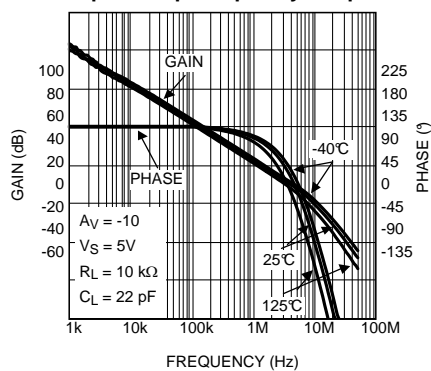
**Output Voltage  
vs.  
Output Current**



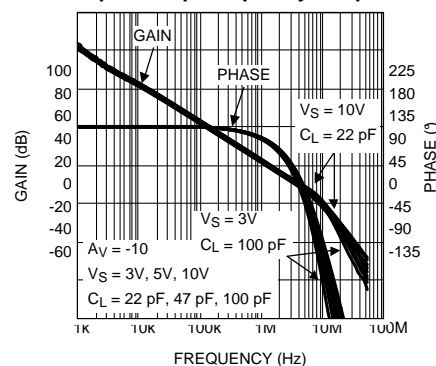
**Slew Rate  
vs.  
Supply Voltage**



**Open Loop Frequency Response**



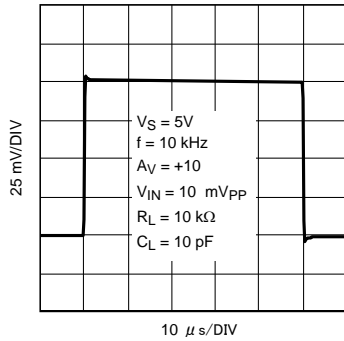
**Open Loop Frequency Response**



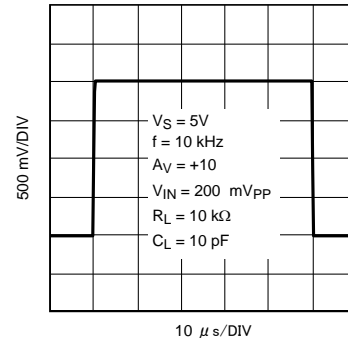
## Typical Performance Characteristics (continued)

Unless otherwise specified,  $T_A = 25^\circ\text{C}$ ,  $V_{CM} = V_S/2$ ,  $R_L > 10\text{ k}\Omega$  connected to  $(V^+ + V^-)/2$

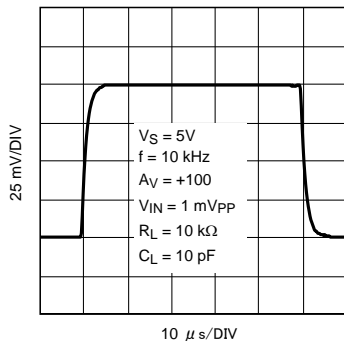
**Small Signal Step Response,  $A_V = 10$**



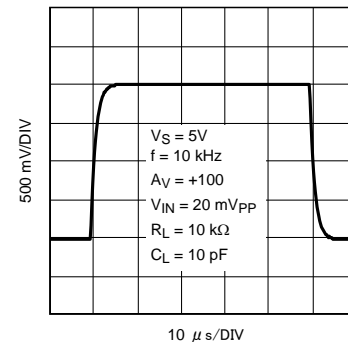
**Large Signal Step Response,  $A_V = 10$**



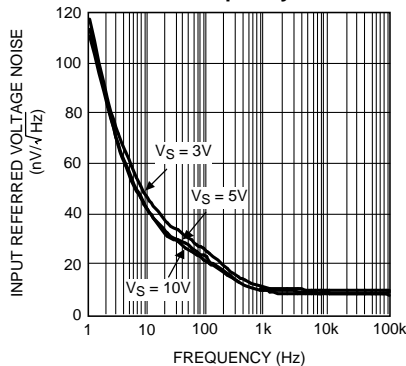
**Small Signal Step Response,  $A_V = 100$**



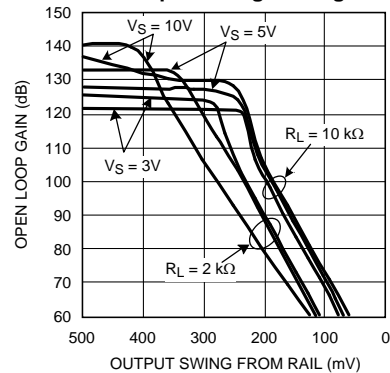
**Large Signal Step Response,  $A_V = 100$**



**Input Voltage Noise  
vs.  
Frequency**



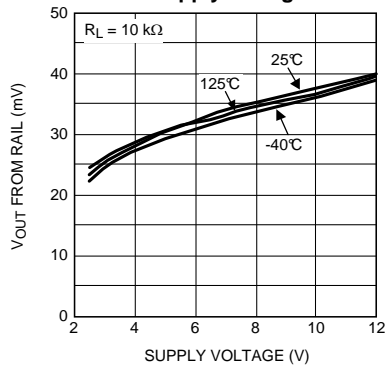
**Open Loop Gain  
vs.  
Output Voltage Swing**



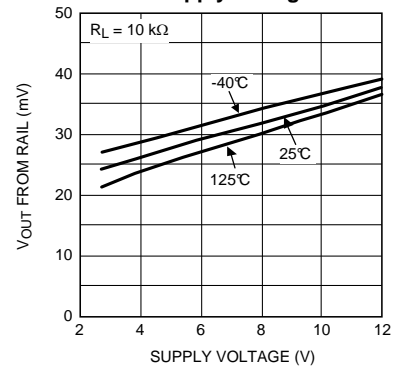
### Typical Performance Characteristics (continued)

Unless otherwise specified,  $T_A = 25^\circ\text{C}$ ,  $V_{CM} = V_S/2$ ,  $R_L > 10\text{ k}\Omega$  connected to  $(V^+ + V^-)/2$

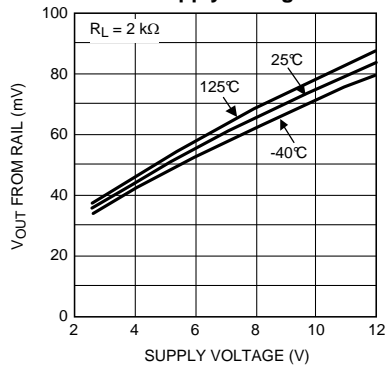
**Output Swing High  
vs.  
Supply Voltage**



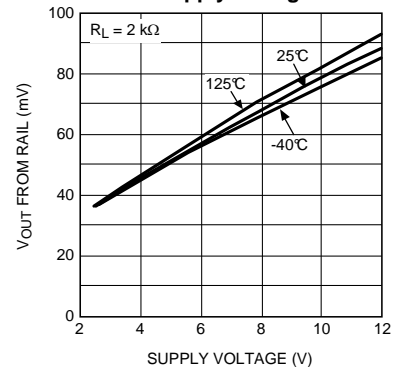
**Output Swing Low  
vs.  
Supply Voltage**



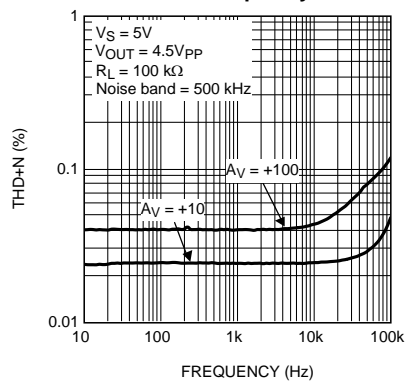
**Output Swing High  
vs.  
Supply Voltage**



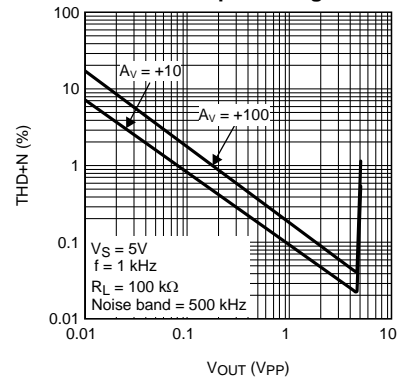
**Output Swing Low  
vs.  
Supply Voltage**



**THD+N  
vs.  
Frequency**



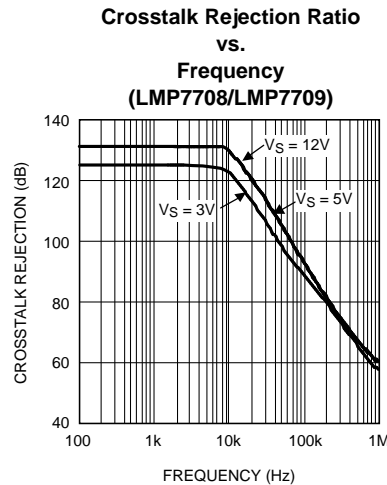
**THD+N  
vs.  
Output Voltage**





## Typical Performance Characteristics (continued)

Unless otherwise specified,  $T_A = 25^\circ\text{C}$ ,  $V_{CM} = V_S/2$ ,  $R_L > 10\text{ k}\Omega$  connected to  $(V^+ + V^-)/2$



## Application Information

### LMP7707/LMP7708/LMP7709

The LMP7707/LMP7708/LMP7709 devices are single, dual and quad low offset voltage, rail-to-rail input and output precision amplifiers each with a CMOS input stage and the wide supply voltage range of 2.7V to 12V. The LMP7707/LMP7708/LMP7709 have a very low input bias current of only  $\pm 200\text{ fA}$  at room temperature.

The wide supply voltage range of 2.7V to 12V over the extensive temperature range of  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  makes either the LMP7707, LMP7708 or LMP7709 an excellent choice for low voltage precision applications with extensive temperature requirements.

The LMP7707/LMP7708/LMP7709 have only  $\pm 37\text{ }\mu\text{V}$  of typical input referred offset voltage and this offset is guaranteed to be less than  $\pm 500\text{ }\mu\text{V}$  for the single and  $\pm 520\text{ }\mu\text{V}$  for the dual and quad over temperature. This minimal offset voltage allows more accurate signal detection and amplification in precision applications.

The low input bias current of only  $\pm 200\text{ fA}$  along with the low input referred voltage noise of  $9\text{ nV}/\sqrt{\text{Hz}}$  give the LMP7707/LMP7708/LMP7709 superior qualities for use in sensor applications. Lower levels of noise introduced by the amplifier mean better signal fidelity and a higher signal-to-noise ratio.

The LMP7707/LMP7708/LMP7709 are stable for a gain of 6 or higher. With proper compensation though, the LMP7707, LMP7708 or LMP7709 can be operational at a gain of  $\pm 1$  and still maintain much faster slew rates than comparable fully compensated amplifiers. The increase in bandwidth and slew rate is obtained without any additional power consumption.

National Semiconductor is heavily committed to precision amplifiers and the market segment they serve. Technical support and extensive characterization data is available for sensitive applications or applications with a constrained error budget.

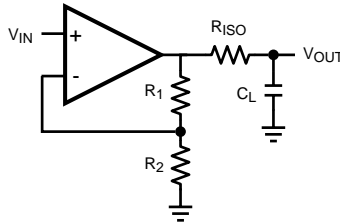
The LMP7707 is offered in the space saving 5-Pin SOT23 and 8-Pin SOIC package, the LMP7708 comes in the 8-pin MSOP and 8-Pin SOIC package and the LMP7709 is offered in the 14-Pin TSSOP and 14-Pin SOIC package. These small packages are ideal solutions for area constrained PC boards and portable electronics.

### CAPACITIVE LOAD

The LMP7707/LMP7708/LMP7709 devices can each be connected as a non-inverting voltage follower. This configuration is the most sensitive to capacitive loading.

The combination of a capacitive load placed on the output of an amplifier along with the amplifier's output impedance creates a phase lag which in turn reduces the phase margin of the amplifier. If the phase margin is significantly reduced, the response will be either underdamped or it will oscillate.

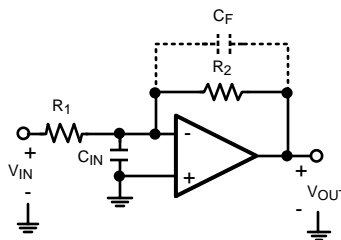
In order to drive heavier capacitive loads, an isolation resistor,  $R_{ISO}$ , as shown in the circuit in Figure 6 should be used. By using this isolation resistor, the capacitive load is isolated from the amplifier's output, and hence, the pole caused by  $C_L$  is no longer in the feedback loop. The larger the value of  $R_{ISO}$ , the more stable the output voltage will be. If values of  $R_{ISO}$  are sufficiently large, the feedback loop will be stable, independent of the value of  $C_L$ . However, larger values of  $R_{ISO}$  result in reduced output swing and reduced output current drive.



**Figure 6. Isolating Capacitive Load**

## INPUT CAPACITANCE

CMOS input stages inherently have low input bias current and higher input referred voltage noise. The LMP7707/LMP7708/LMP7709 enhances this performance by having the low input bias current of only  $\pm 200$  fA, as well as a very low input referred voltage noise of  $9 \text{ nV}/\sqrt{\text{Hz}}$ . In order to achieve this a large input stage has been used. This large input stage increases the input capacitance of the LMP7707/LMP7708/LMP7709. The typical value of this input capacitance,  $C_{IN}$ , for the LMP7707/LMP7708/LMP7709 is 25 pF. The input capacitance will interact with other impedances such as gain and feedback resistors, which are seen on the inputs of the amplifier, to form a pole. This pole will have little or no effect on the output of the amplifier at low frequencies and DC conditions, but will play a bigger role as the frequency increases. At higher frequencies, the presence of this pole will decrease phase margin and will also cause gain peaking. In order to compensate for the input capacitance, care must be taken in choosing the feedback resistors. In addition to being selective in picking values for the feedback resistor, a capacitor can be added to the feedback path to increase stability.



**Figure 7. Compensating for Input Capacitance**

Using this compensation method will have an impact on the high frequency gain of the op amp, due to the frequency dependent feedback of this amplifier. Low gain settings can, again, introduce instability issues.

## DIODES BETWEEN THE INPUTS

The LMP7707/LMP7708/LMP7709 have a set of anti-parallel diodes between the input pins, as shown in Figure 8. These diodes are present to protect the input stage of the amplifier. At the same time, they limit the amount of differential input voltage that is allowed on the input pins. A differential signal larger than one diode voltage drop might damage the diodes. The differential signal between the inputs needs to be limited to  $\pm 300$  mV or the input current needs to be limited to  $\pm 10$  mA. Exceeding these limits will damage the part.

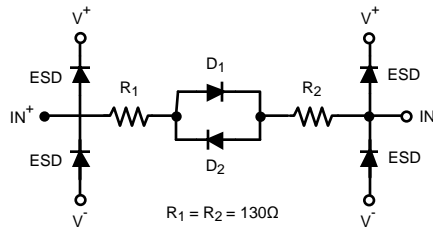


Figure 8. Input of the LMP7707

## TOTAL NOISE CONTRIBUTION

The LMP7707/LMP7708/LMP7709 have very low input bias current, very low input current noise and very low input voltage noise. As a result, these amplifiers are ideal choices for circuits with high impedance sensor applications.

Figure 9 shows the typical input noise of the LMP7707/LMP7708/LMP7709 as a function of source resistance. The total noise at the input can be calculated using Equation 1.

$$e_{ni} = \sqrt{e_n^2 + e_i^2 + e_t^2} \quad (1)$$

Where:

$e_{ni}$  is the total noise on the input.

$e_n$  denotes the input referred voltage noise

$e_i$  is the voltage drop across source resistance due to input referred current noise or  $e_i = R_S * i_n$

$e_t$  is the thermal noise of the source resistance

The input current noise of the LMP7707/LMP7708/LMP7709 is so low that it will not become the dominant factor in the total noise unless source resistance exceeds 300 MΩ, which is an unrealistically high value.

As is evident in Figure 9, at lower  $R_S$  values, the total noise is dominated by the amplifier's input voltage noise. Once  $R_S$  is larger than a few kilo-Ohms, then the dominant noise factor becomes the thermal noise of  $R_S$ . As mentioned before, the current noise will not be the dominant noise factor for any practical application.

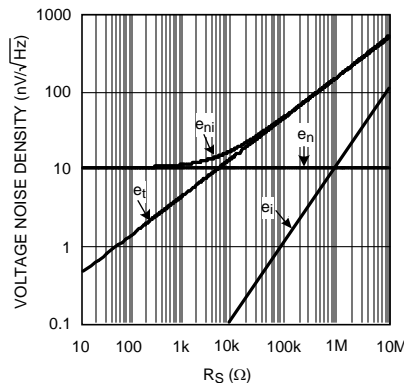
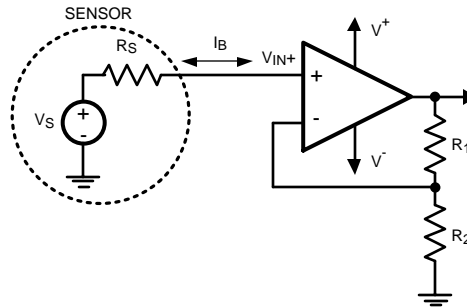


Figure 9. Total Input Noise

## HIGH IMPEDANCE SENSOR INTERFACE

Many sensors have high source impedances that may range up to 10 MΩ. The output signal of sensors often needs to be amplified or otherwise conditioned by means of an amplifier. The input bias current of this amplifier can load the sensor's output and cause a voltage drop across the source resistance as shown in Figure 10, where  $V_{IN+} = V_S - I_{BIAS} * R_S$

The last term,  $I_{\text{BIAS}} \cdot R_S$ , shows the voltage drop across  $R_S$ . To prevent errors introduced to the system due to this voltage, an op amp with very low input bias current must be used with high impedance sensors. This is to keep the error contribution by  $I_{\text{BIAS}} \cdot R_S$  less than the input voltage noise of the amplifier, so that it will not become the dominant noise factor. The LMP7707/LMP7708/LMP7709 have very low input bias current, typically 200 fA.



**Figure 10. Noise Due to  $I_{\text{BIAS}}$**

## USAGE OF DECOMPENSATED AMPLIFIERS

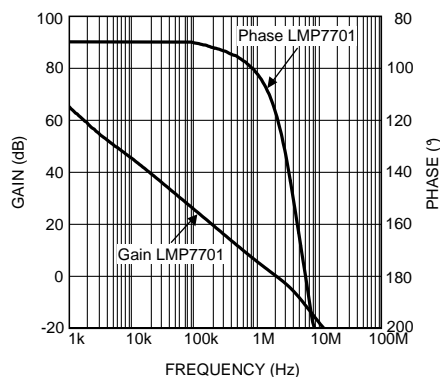
This section discusses the differences between compensated and decompensated op amps and presents the advantages of decompensated amplifiers. In high gain applications decompensated amplifiers can be used without any changes compared to standard amplifiers. However, for low gain applications special frequency compensation measures have to be taken to ensure stability.

Feedback circuit theory is discussed in detail, in particular as it applies to decompensated amplifiers. Bode plots are presented for a graphical explanation of stability analysis. Two solutions are given for creating a feedback network for decompensated amplifiers when relatively low gains are required: A simple resistive feedback network and a more advanced frequency dependent feedback network with improved noise performance. Finally, a design example is presented resulting in a practical application. The results are compared to fully compensated amplifiers (National Semiconductors LMP7701/LMP7702/LMP7704).

## COMPENSATED AMPLIFIERS

A (fully) compensated op amp is designed to operate with good stability down to gains of  $\pm 1$ . For this reason, the compensated op amp is also called a unity gain stable op amp.

Figure 11 shows the Open Loop Response of a compensated amplifier.



**Figure 11. Open Loop Frequency Response Compensated Amplifier (LMP7701)**

This amplifier is unity gain stable, because the phase shift is still  $< 180^\circ$ , when the gain crosses 0 dB (unity gain). Stability can be expressed in two different ways:

**Phase Margin** This is the phase difference between the actual phase shift and  $180^\circ$ , at the point where the gain is 0 dB.

**Gain Margin** This is the gain difference relative to 0 dB, at the frequency where the phase shift crosses the 180°.

The amplifier is supposed to be used with negative feedback but a phase shift of 180° will turn the negative feedback into positive feedback, resulting in oscillations. A phase shift of 180° is not a problem when the gain is smaller than 0 dB, so the critical point for stability is 180° phase shift at 0 dB gain. The gain margin and phase margin express the margin enhancing overall stability between the amplifiers response and this critical point.

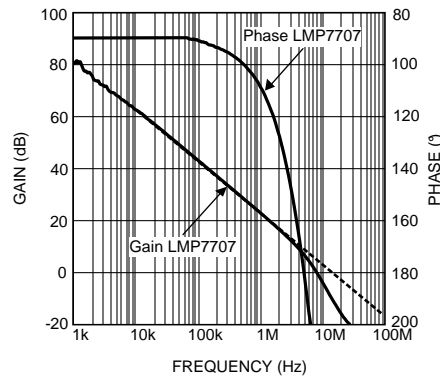
## DECOMPENSATED AMPLIFIERS

Decompensated amplifiers, such as the LMP7707/LMP7708/LMP7709, are designed to maximize the bandwidth and slew rate without any additional power consumption over the unity gain stable op amp. That is, a decompensated op amp has a higher bandwidth to power ratio than an equivalent compensated op amp. Compared with the unity gain stable amplifier, the decompensated version has the following advantages:

1. A wider closed loop bandwidth.
2. Better slew rate due to reduced compensation capacitance within the op amp.
3. Better Full Power Bandwidth, given with [Equation 2](#).

$$FPBW = \frac{SR}{2\pi V_P} \quad (2)$$

[Figure 12](#) shows the frequency response of the decompensated amplifier.



**Figure 12. Open Loop Frequency Response Decompensated Amplifier (LMP7707)**

As shown in [Figure 12](#), the reduced internal compensation moves the first pole to higher frequencies. The second open loop pole for the LMP7707/LMP7708/LMP7709 occurs at 4 MHz. The extrapolated unity gain (see dashed line in [Figure 12](#)) occurs at 14 MHz. An ideal two pole system would give a phase margin of > 45° at the location of the second pole. Unfortunately, the LMP7707/LMP7708/LMP7709 have parasitic poles close to the second pole, giving a phase margin closer to 0°. The LMP7707/LMP7708/LMP7709 can be used at frequencies where the phase margin is > 45°. The frequency where the phase margin is 45° is at 2.4 MHz. The corresponding value of the open loop gain (also called  $G_{MIN}$ ) is 6 times.

Stability has only to do with the loop gain and not with the forward gain (G) of the op amp. For high gains, the feedback network is attenuating and this reduces the loop gain; therefore the op amp will be stable for  $G > G_{MIN}$  and no special measures are required. For low gains the feedback network attenuation may not be sufficient to ensure loop stability for a decompensated amplifier. However, with an external compensation network decompensated amplifiers can still be made stable while maintaining their advantages over unity gain stable amplifiers.

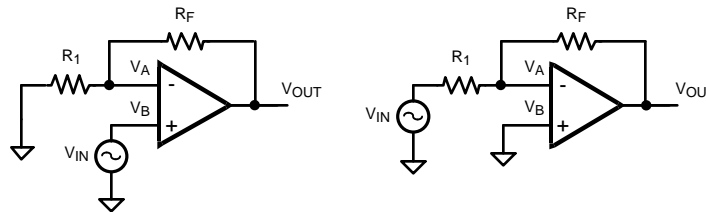
## EXTERNAL COMPENSATION FOR GAINS LOWER THAN $G_{MIN}$ .

This section explains how decompensated amplifiers can be used in configurations requiring a gain lower than  $G_{MIN}$ . In the next sections the concept of the feedback factor is introduced. Subsequently, an explanation is given how stability can be determined using the frequency response curve of the op amp together with the feedback factor. Using the circuit theory, it will be explained how decompensated amplifiers can be stabilized at lower gains.

## FEEDBACK THEORY

Stability issues can be analyzed by verifying the loop gain function  $GF$ , where  $G$  is the open loop gain of the amplifier and  $F$  is the feedback factor of the feedback circuit.

The feedback function ( $F$ ) of arbitrary electronic circuits, as shown in Figure 13, is defined as the ratio of the input and output signal of the same circuit.



**Figure 13. Op Amp with Resistive Feedback. (a) Non-inverting (b) Inverting**

The feedback function for a three-terminal op amp as shown in Figure 13 is the feedback voltage  $V_A - V_B$  across the op amp input terminals relative to the op amp output voltage,  $V_{OUT}$ . That is

$$F = \frac{V_A - V_B}{V_{OUT}} \quad (3)$$

## GRAPHICAL EXPLANATION OF STABILITY ANALYSIS

Stability issues can be observed by verifying the closed loop gain function  $GF$ . In the frequencies of interest, the open loop gain ( $G$ ) of the amplifier is a number larger than 1 and therefore positive in dB. The feedback factor ( $F$ ) of the feedback circuit is an attenuation and therefore negative in dB. For calculating the closed loop gain  $GF$  in dB we can add the values of  $G$  and  $F$  (both in dB).

One practical approach to stabilizing the system, is to assign a value to the feedback factor  $F$  such that the remaining loop gain  $GF$  equals one (unity gain) at the frequency of  $G_{MIN}$ . This realizes a phase margin of  $45^\circ$  or greater. This results in the following requirement for stability:  $1/F > G_{MIN}$ . The inverse feedback factor  $1/F$  is constant over frequency and should intercept the open loop gain at a value in dB that is greater than or equal to  $G_{MIN}$ .

The inverse feedback factor for both configurations shown in Figure 13, is given by:

$$\frac{1}{F} = 1 + \frac{R_F}{R_1} \quad (4)$$

The closed loop gain for the non-inverting configuration (a) is:

$$A_{CL} = 1 + \frac{R_F}{R_1} = \frac{1}{F} \quad (5)$$

The closed loop gain for the inverting configuration (b) is:

$$A_{CL} = -\frac{R_F}{R_1} = 1 - \frac{1}{F} \quad (6)$$

For stable operation the phase margin must be equal to or greater than  $45^\circ$ . The corresponding closed loop gain  $G_{MIN}$ , for a non-inverting configuration, is

$$|A_{CL}|(\min) = G_{\min} \quad (7)$$

For an inverting configuration:

$$|A_{CL}|(\min) = G_{\min} - 1 \quad (8)$$

If  $R_1$  and  $R_F$  are chosen so that the closed loop gain is lower than the minimum gain required for stability, then  $1/F$  intersects the open loop gain curve for a value that is lower than  $G_{MIN}$ . For example, assume the  $G_{MIN}$  is equal to 10 V/V (20 dB). This is shown as the dashed line in Figure 14. The resistor choice of  $R_F = R_1 = 2\text{ k}\Omega$  makes the inverse feedback equal 2 V/V (6 dB), shown in Figure 14 as the solid line. The intercept of  $G$  and  $1/F$  represents the frequency for which the loop gain is identical to 1 (0 dB). Consequently, the total phase shift at the frequency of this intercept determines the phase margin and the overall system stability. In this system example  $1/F$  crosses the open loop gain at a frequency which is larger than the frequency where  $G_{MIN}$  occurs, therefore this system has less than  $45^\circ$  phase margin and is most likely unstable.

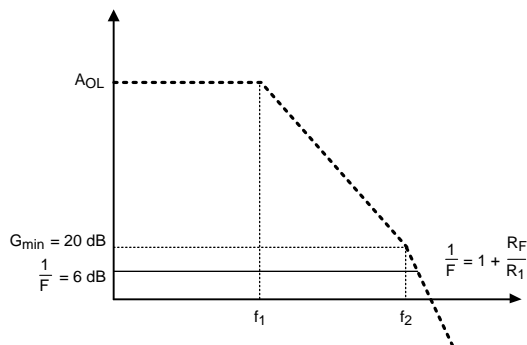


Figure 14.  $1/F$  for  $R_F = R_1$  and Open Loop Gain Plot

## RESISTIVE COMPENSATION

A straightforward way to achieve a stable amplifier configuration is to add a resistor  $R_C$  between the inverting and the non-inverting inputs as shown in Figure 15.

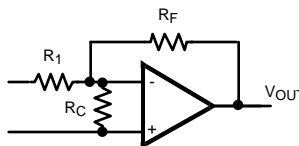


Figure 15. Op Amp with Compensation Resistor between Inputs

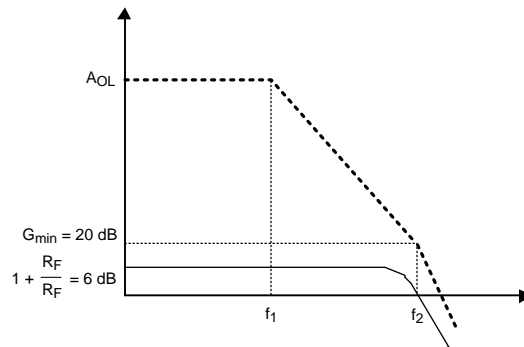
This additional resistor  $R_C$  will not affect the closed loop gain of the amplifier but it will have positive impact on the feedback network.

The inverse feedback function of this circuit is:

$$\frac{1}{F} = 1 + \frac{R_F}{R_1 // R_C} = 1 + \frac{R_F}{R_1} + \frac{R_F}{R_C} \quad (9)$$

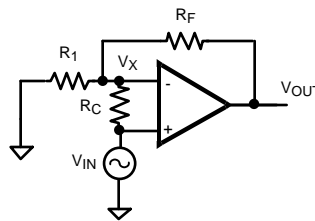
Proper selection of the value of  $R_C$  results in the shifting of the  $1/F$  function to  $G_{MIN}$  or greater, thus fulfilling the condition for circuit stability. The compensation technique of reducing the loop gain may be used to stabilize the circuit for the values given in the previous example, that is  $G_{MIN} = 20\text{ dB}$  and  $R_F = R_1 = 2\text{ k}\Omega$ . A resistor value of  $250\text{ }\Omega$  applied between the amplifier inputs shifts the  $1/F$  curve to the value  $G_{MIN}$  (20 dB) as shown by the dashed line in Figure 16. This results in overall stability for the circuit. This figure shows a combination of the open and closed loop gain and the inverse feedback function.

This example, represented by Figure 13 and Figure 14, is generic in the sense that the  $G_{MIN}$  as specified did not distinguish between inverting and non-inverting configurations.



**Figure 16. Compensation with Reduced Loop Gain**

The technique of reducing loop gain to stabilize a decompensated op amp circuit will be illustrated using the non-inverting input configuration shown in [Figure 17](#).



**Figure 17. Closed Loop Gain Analysis with  $R_C$**

The effect of the choice of resistor  $R_C$  in [Figure 17](#) on the closed loop gain can be analyzed in the following manner:

Assume the voltage at the inverting input of the op amp is  $V_X$ . Then,

$$(V_{IN} - V_X) G = V_{OUT} \quad (10)$$

Where  $G$  is the open loop gain of the op amp.

$$\frac{V_X}{R_1} + \frac{V_X - V_{IN}}{R_C} = \frac{V_{OUT} - V_X}{R_F} \quad (11)$$

Combining [Equation 10](#), [Equation 11](#), and [Equation 9](#) produces the following equation for closed loop gain,

$$\frac{V_{OUT}}{V_{IN}} = \frac{1 + \frac{R_F}{R_1}}{1 + \frac{1}{GF}} \quad (12)$$

By inspection of [Equation 12](#),  $R_C$  does not affect the ideal closed loop gain. In this example where  $R_F = R_1$ , the closed loop gain remains at 6 dB as long as  $GF \gg 1$ . The closed loop gain curve is shown as the solid line in [Figure 16](#).

The addition of  $R_C$  affects the circuit in the following ways:

1.  $1/F$  is moved to a higher gain, resulting in overall system stability.

However, adding  $R_C$  results in reduced loop gain and increased noise gain. The noise gain is defined as the inverse of the feedback factor,  $F$ . The noise gain is the gain from the amplifier input referred noise to the output. In effect, loop gain is traded for stability.

2. The ideal closed loop gain retains the same value as the circuit without the compensation resistor  $R_C$ .

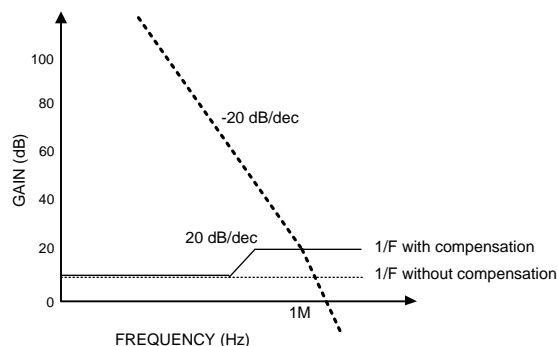


## LEAD-LAG COMPENSATION

This section presents a more advanced compensation technique that can be used to stabilize amplifiers. The increased noise gain of the prior circuit is prevented by reducing the low frequency attenuation of the feedback circuit. This compensation method is called Lead-Lag compensation. Lead-lag compensation components will be analyzed and a design example using this procedure will be discussed.

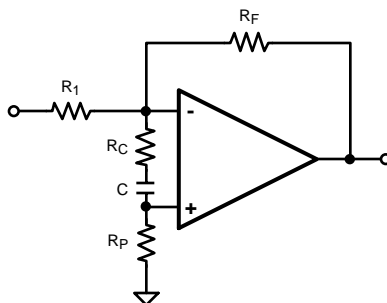
The feedback function in a lead-lag compensation circuit is shaped using a resistor and a capacitor. They are chosen in a way that ensures sufficient phase margin.

Figure 18 shows a Bode plot containing: the open loop gain of the decompensated amplifier, a feedback function without compensation and a feedback function with lead-lag compensation.



**Figure 18. Bode Plot of Open Loop gain G and 1/F with and without Lead-Lag Compensation**

The shaped feedback function presented in Figure 18 can be realized using the amplifier configuration in Figure 19. Note that resistor  $R_P$  is only used for compensation of the input voltage caused by the  $I_{BIAS}$  current.  $R_P$  can be used to introduce more freedom for calculating the lead-lag components. This will be discussed later in this section.



**Figure 19. LMP7707 with Lead-Lag Compensation for Inverting Configuration**

The inverse feedback factor of the circuit in Figure 19 is:

$$\frac{1}{F} = \left(1 + \frac{R_F}{R_1}\right) \left(\frac{1 + s(R_C + R_1//R_F + R_P)C}{1 + sR_C C}\right) \quad (13)$$

The pole of the inverse feedback function is located at:

$$f_P = \frac{1}{2\pi R_C C} \quad (14)$$

The zero of the inverse feedback function is located at:

$$f_Z = \frac{1}{2\pi(R_C + R_1//R_F + R_P) C} \quad (15)$$

The low frequency inverse feedback factor is given by:

$$\left. \frac{1}{F} \right|_{f=0} = 1 + \frac{R_F}{R_1} \quad (16)$$

The high frequency inverse feedback factor is given by:

$$\left. \frac{1}{F} \right|_{f=\infty} = \left(1 + \frac{R_F}{R_1}\right) \left(1 + \frac{R_P + R_1 // R_F}{R_C}\right) \quad (17)$$

From these formulas, we can tell that

1. The 1/F's zero is located at a lower frequency compared to 1/F's pole.
2. The intersection point of 1/F and the open loop gain G is determined by the choice of resistor values for  $R_P$  and  $R_C$  if the values of  $R_1$  and  $R_F$  are set before compensation.
3. This procedure results in the creation of a pole-zero pair, the positions of which are interdependent.
4. This pole-zero pair is used to:
  - Raise the 1/F value to a greater value in the region immediately to the left of its intercept with the A function in order to meet the  $G_{min}$  requirement.
  - Achieve the preceding with no additional loop phase delay.
5. The location of the 1/F zero is determined by the following conditions:
  - The value of 1/F at low frequency.
  - The value of 1/F at the intersection point.
  - The location of 1/F pole.

Note that the constraint  $1/F \geq G_{min}$  needs to be satisfied only in the vicinity of the intersection of G and 1/F; 1/F can be shaped elsewhere as needed. Two rules must be satisfied in order to maintain adequate phase margin.

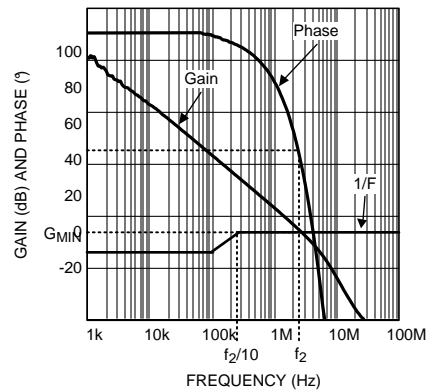
**Rule 1** The plot of 1/F should intersect with the plot of the open loop gain at a value larger than  $G_{MIN}$ . At that point, the open loop gain G has a phase margin of 45°. The location  $f_2$  in [Figure 20](#) illustrates the proper intersection point for the LMP7707/LMP7708/LMP7709 using the circuit of [Figure 19](#). The intersection of G and 1/F at the op amp's second pole location is the 45° phase margin reference point.

**Rule 2** The 1/F pole (see [Figure 20](#)) should be positioned at the frequency that is at least one decade below the intersection point  $f_2$  of 1/F and G. This positioning takes full advantage of the 90° of phase lead brought about by the 1/F pole. This additional phase lead accompanies the increase in magnitude of 1/F observed at frequencies greater than the 1/F pole.

The resulting system has approximately 45° of phase margin, based upon the fact that the open loop gain's dominant pole and the second pole are more than one decade apart and that the open loop gain has no other pole within one decade of its intersection point with 1/F. If there is a third pole in the open loop gain G at a frequency greater than  $f_2$  and if it occurs less than a decade above that frequency, then there will be an effect on phase margin.

## DESIGN EXAMPLE

The input lead-lag compensation method can be applied to an application using the LMP7707, LMP7708 or LMP7709 in an inverting configuration, as shown in [Figure 19](#).



**Figure 20. LMP7707 Open Loop Gain and 1/F Lead-Lag Feedback Network.**

Figure 20 shows that  $G_{MIN} = 16$  dB and  $f_2$  (intersection point) = 2.4 MHz.

A gain of 6 dB (or a magnitude of  $-1$ ) is well below the LMP7707's  $G_{MIN}$ . Without external lead-lag compensation, the inverse feedback factor is found using Equation 4 which applies to both inverting and non-inverting configurations. Unity gain implementation for the inverting configuration means  $R_F = R_1$ , and  $1/F = 2$  (6 dB).

#### Procedure:

The compensation circuit shown in Figure 19 is implemented. The inverse feedback function is shaped by the solid line in Figure 20. The 1/F plot is 6 dB at low frequencies. At higher frequencies, it is made to intersect the loop gain  $G$  at frequency  $f_2$  with gain amplitude of 16 dB ( $G_{MIN}$ ), which equals a magnitude of six times. This follows the recommendations in Rule 1. The 1/F pole  $f_p$  is set one decade below the intersection point ( $f_2 = 2.4$  MHz) as given in Rule 2, and results in a frequency  $f_p = 240$  kHz. The next steps should be taken to calculate the values of the compensation components:

**Step 1)** Set 1/F equal to  $G_{MIN}$  using Equation 17. This gives a value for resistor  $R_C$ .

**Step 2)** Set the 1/F pole one decade below the intersection point using Equation 14. This gives a value for capacitor  $C$ .

This method uses bode plot approximation. Some fine-tuning may be needed to get the best results.

#### Calculations:

As described in Step 1, use Equation 17.

$$\frac{1}{F} \Big|_{f=\infty} = \left(1 + \frac{R_F}{R_1}\right) \left(1 + \frac{R_P + R_1 // R_F}{R_C}\right) = 6 \text{ V/V} \quad (18)$$

Now substitute  $R_F/R_1 = 1$  into the equation above since this is a unity gain, inverting amplifier, then

$$R_P + R_1 // R_F = 2 R_C \quad (19)$$

According to Step 2 use Equation 14

$$f_p = \frac{1}{2\pi R_C C} = 240 \text{ kHz} \quad (20)$$

which leads to:

$$C = \frac{1}{2\pi f_p R_C} \quad (21)$$

Choose a value of  $R_F$  that is below 2 k $\Omega$ , in order to minimize the possibility of shunt capacitance across high value resistors producing a negative effect on high frequency operation. If  $R_F = R_1 = 1$  k $\Omega$ , then  $R_F // R_1 = 500$   $\Omega$ . For simplicity, choose  $R_P = 0$   $\Omega$ . The value of  $R_C$  is derived from Equation 19 and has a value of  $R_C = 250$   $\Omega$ . This is not a standard value. A value of  $R_C = 330$   $\Omega$  is a first choice (using 10% tolerance components).

The value of capacitor C is 2.2 nF. This value is significantly higher than the parasitic capacitances associated with passive components and board layout, and is therefore a good solution.

### Bench results:

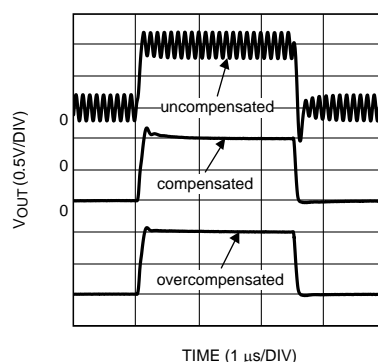
For bench evaluation the LMP7707 in an inverting configuration has been verified under three different conditions:

- Uncompensated.
- Lead-lag compensation resulting in a phase margin of 45°.
- Lead lag overcompensation resulting in a phase margin larger than 45°.

The calculated components for these three conditions are

Condition	$R_C$	C
Uncompensated	NA	NA
Compensated	330 $\Omega$	2.2 nF
Overcompensated	240 $\Omega$	3.3 nF

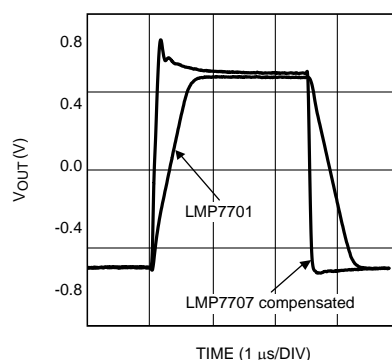
Figure 21 shows the results of the compensation of the LMP7707.



**Figure 21. Bench Results for Lead- Lag Compensation**

The top waveform shows the output response of a uncompensated LMP7707 using no external compensation components. This trace shows ringing and is unstable (as expected). The middle waveform is the response of a compensated LMP7707 using the compensation components calculated with the described procedure. The response is reasonably well behaved. The bottom waveform shows the response of an overcompensated LMP7707.

Finally, Figure 22 compares the step response of the compensated LMP7707 to that of the unity gain stable LMP7701. The increase in dynamic performance is clear.



**Figure 22. Bench Results for Comparison of LMP7701 and LMP7707**

The application of input lead-lag compensation to a decompensated op amp enables the realization of circuit gains of less than the minimum specified by the manufacturer. This is accomplished while retaining the advantageous speed versus power characteristic of decompensated op amps.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMP7707MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		LMP77 07MA	<a href="#">Samples</a>
LMP7707MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		LMP77 07MA	<a href="#">Samples</a>
LMP7707MF/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AH4A	<a href="#">Samples</a>
LMP7707MFX/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AH4A	<a href="#">Samples</a>
LMP7708MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMP77 08MA	<a href="#">Samples</a>
LMP7708MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMP77 08MA	<a href="#">Samples</a>
LMP7708MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AJ4A	<a href="#">Samples</a>
LMP7708MME/NOPB	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AJ4A	<a href="#">Samples</a>
LMP7708MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AJ4A	<a href="#">Samples</a>
LMP7709MA/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		LMP7709 MA	<a href="#">Samples</a>
LMP7709MAX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		LMP7709 MA	<a href="#">Samples</a>
LMP7709MT/NOPB	ACTIVE	TSSOP	PW	14	94	Pb-Free (RoHS)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMP77 09MT	<a href="#">Samples</a>
LMP7709MTX/NOPB	ACTIVE	TSSOP	PW	14	2500	Pb-Free (RoHS)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMP77 09MT	<a href="#">Samples</a>

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

---

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMP7707MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMP7707MF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMP7707MFX/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMP7708MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMP7708MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMP7708MME/NOPB	VSSOP	DGK	8	250	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMP7708MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMP7709MAX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMP7709MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1



## TAPE AND REEL BOX DIMENSIONS

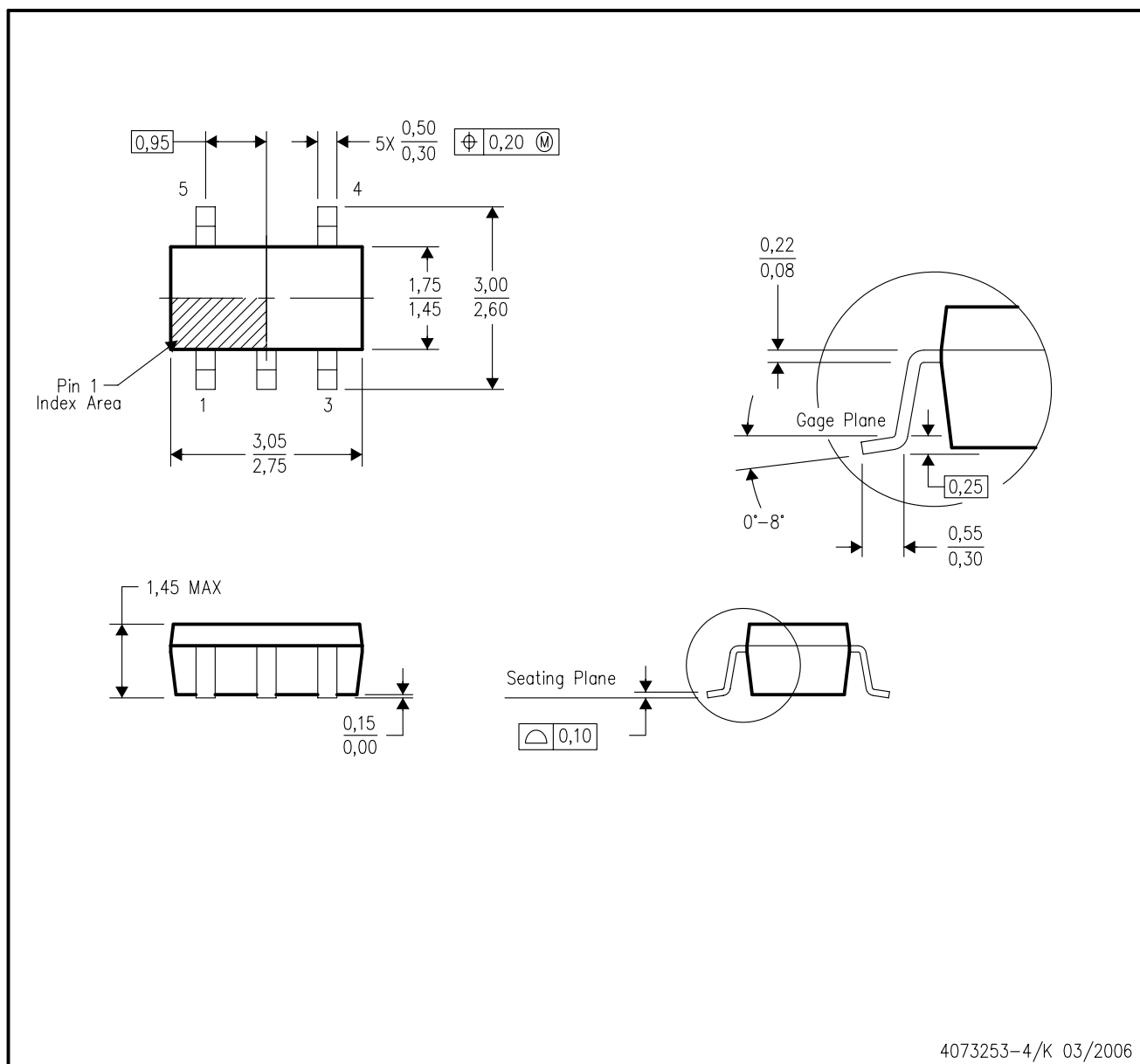


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMP7707MAX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0
LMP7707MF/NOPB	SOT-23	DBV	5	1000	203.0	190.0	41.0
LMP7707MFX/NOPB	SOT-23	DBV	5	3000	206.0	191.0	90.0
LMP7708MAX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0
LMP7708MM/NOPB	VSSOP	DGK	8	1000	203.0	190.0	41.0
LMP7708MME/NOPB	VSSOP	DGK	8	250	203.0	190.0	41.0
LMP7708MMX/NOPB	VSSOP	DGK	8	3500	349.0	337.0	45.0
LMP7709MAX/NOPB	SOIC	D	14	2500	349.0	337.0	45.0
LMP7709MTX/NOPB	TSSOP	PW	14	2500	349.0	337.0	45.0

## DBV (R-PDSO-G5)

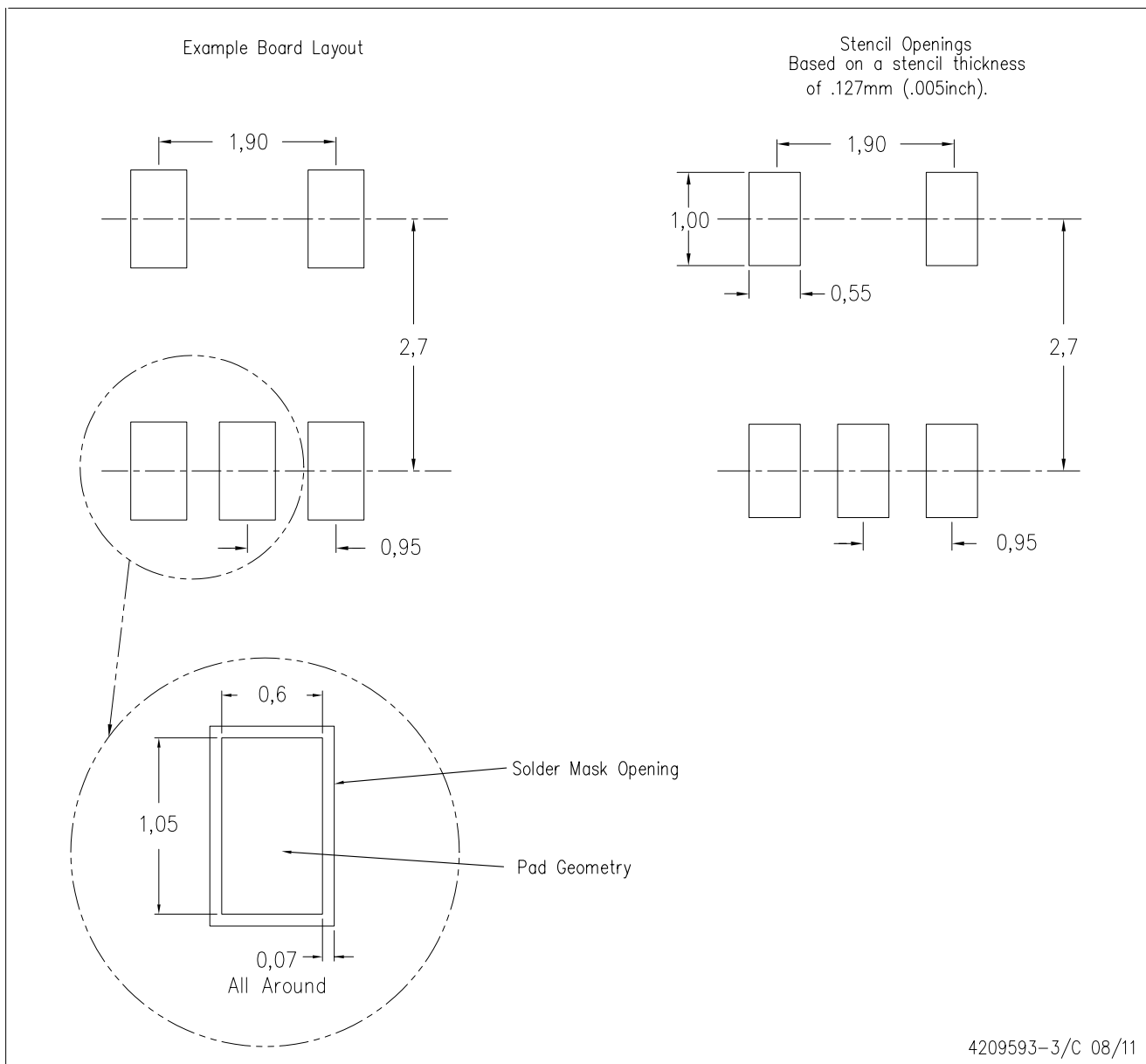
## PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - Falls within JEDEC MO-178 Variation AA.

DBV (R-PDSO-G5)

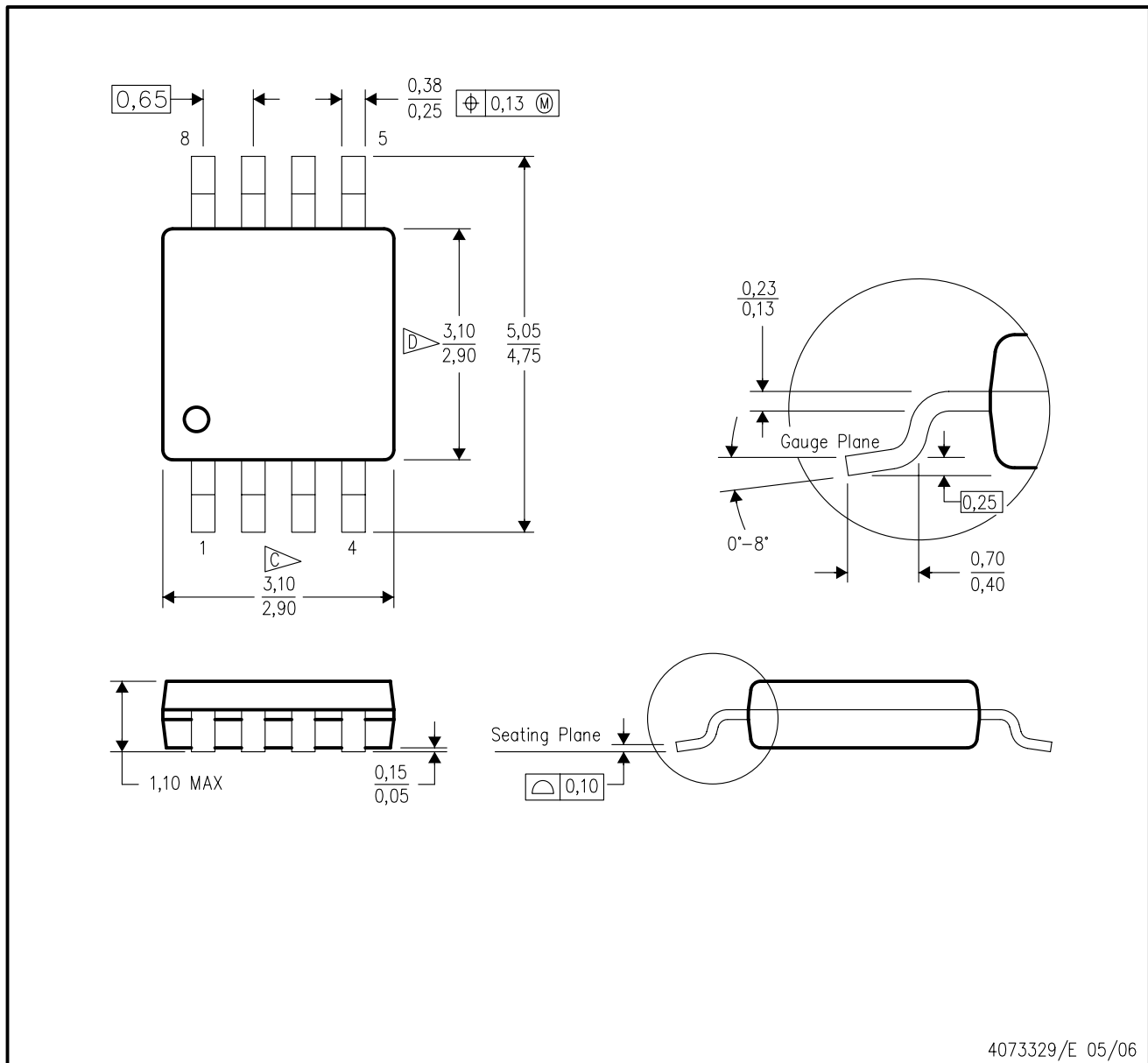
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

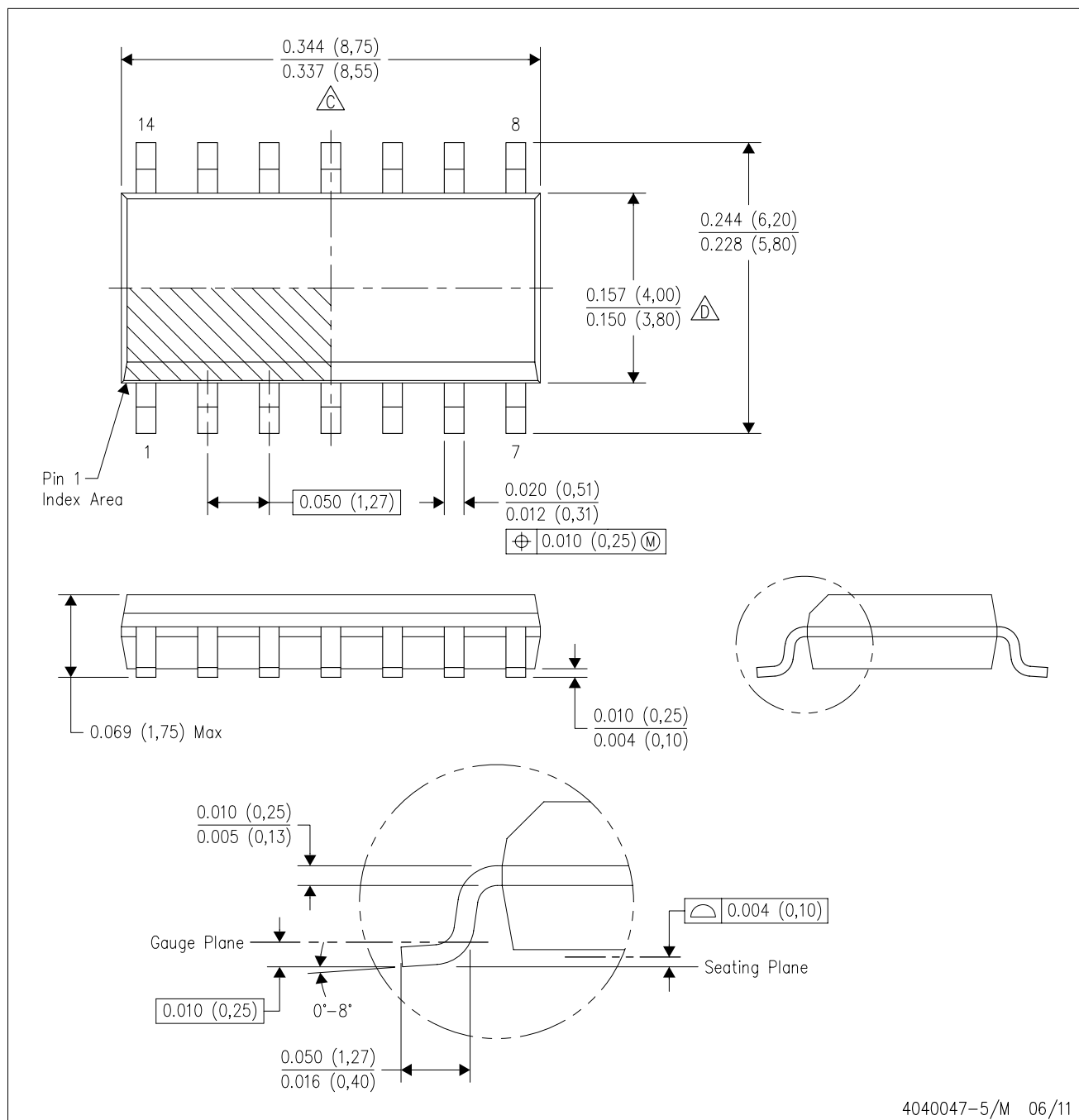


4073329/E 05/06

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
  - E. Falls within JEDEC MO-187 variation AA, except interlead flash.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



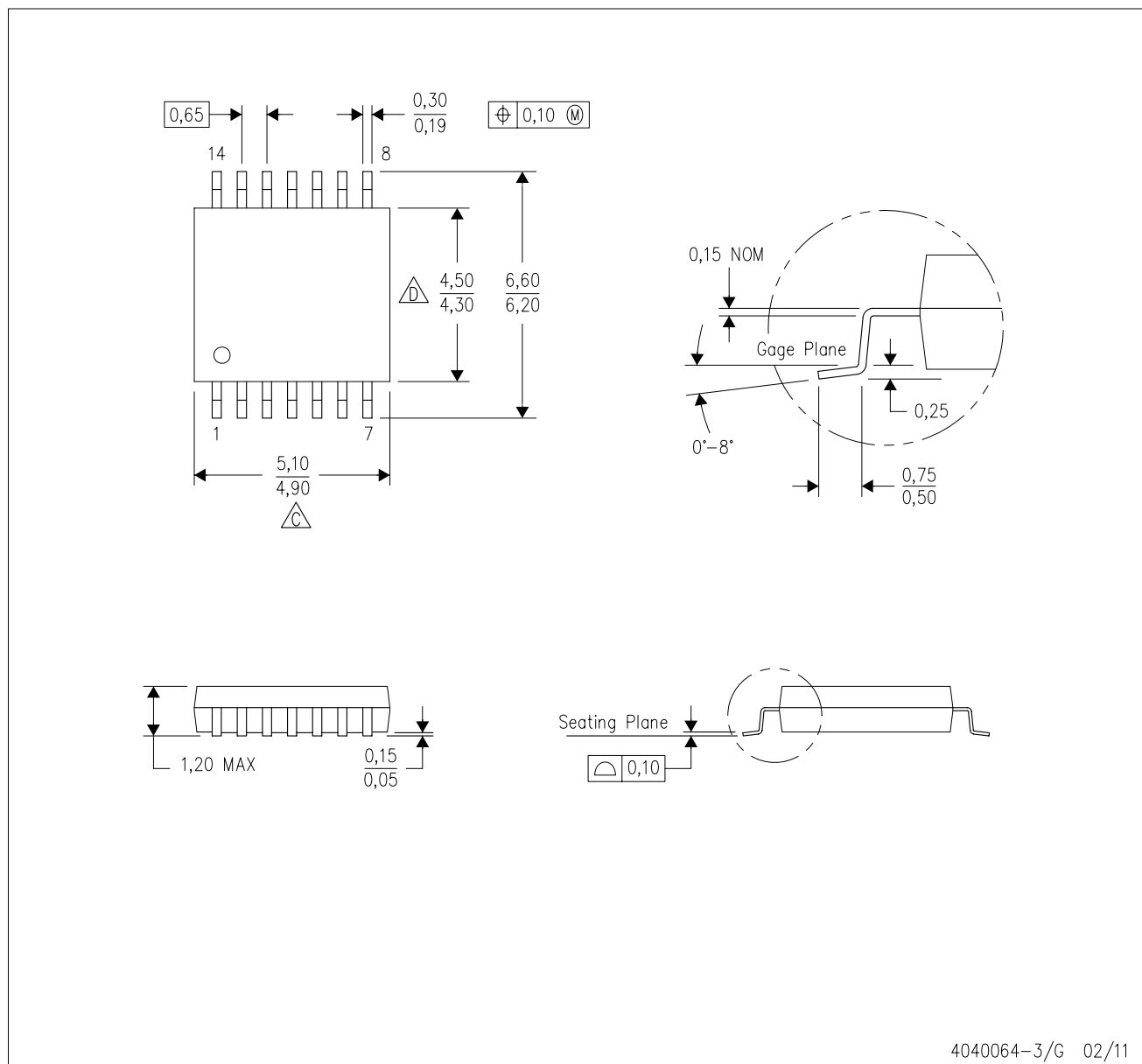
4040047-5/M 06/11

NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.

PW (R-PDSO-G14)

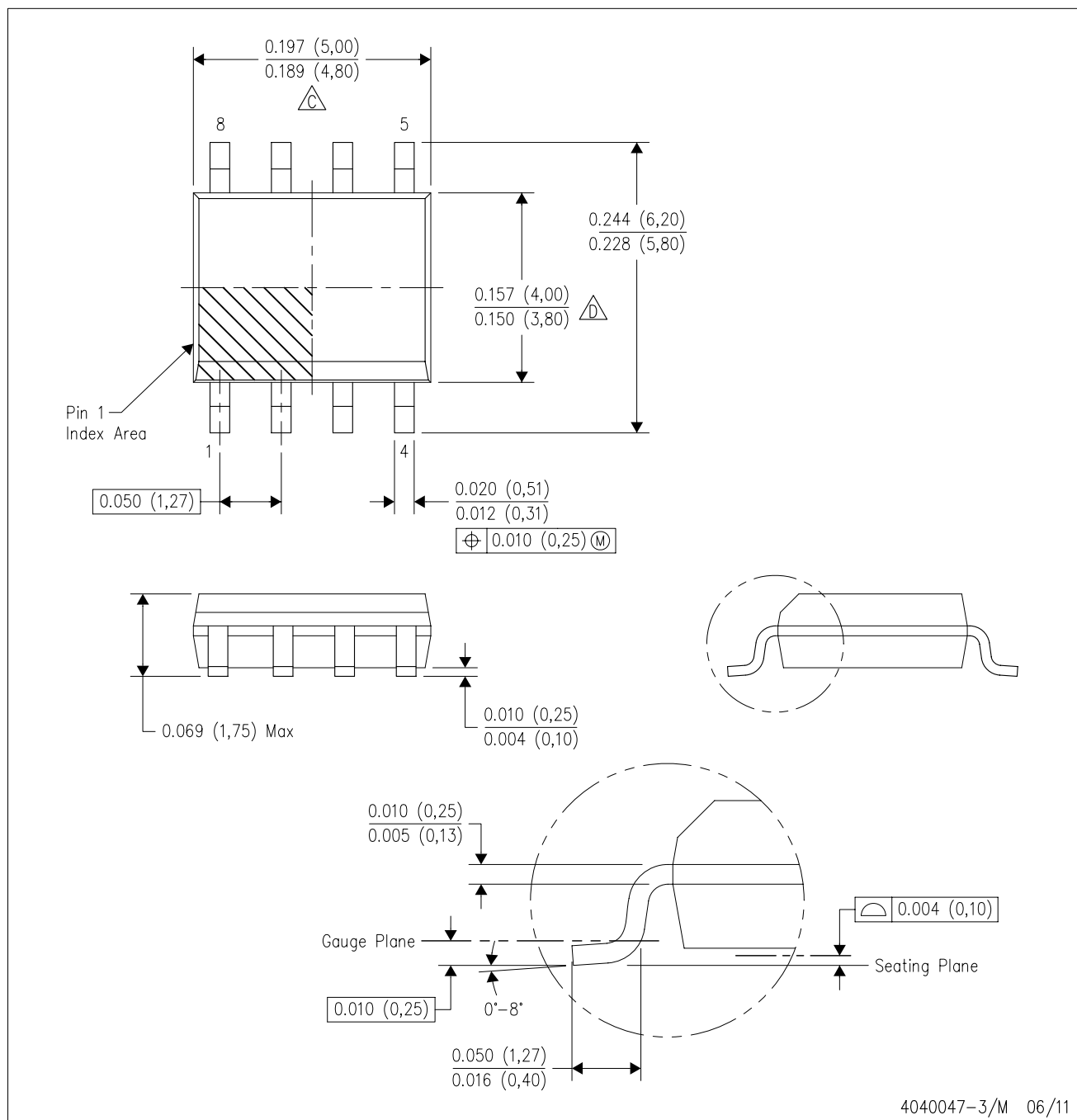
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



## NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- $\triangle C$  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- $\triangle D$  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.

## IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

### Products

Audio	<a href="http://www.ti.com/audio">www.ti.com/audio</a>
Amplifiers	<a href="http://amplifier.ti.com">amplifier.ti.com</a>
Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>
RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>
OMAP Applications Processors	<a href="http://www.ti.com/omap">www.ti.com/omap</a>
Wireless Connectivity	<a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a>

### Applications

Automotive and Transportation	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
Communications and Telecom	<a href="http://www.ti.com/communications">www.ti.com/communications</a>
Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
Consumer Electronics	<a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>
Energy and Lighting	<a href="http://www.ti.com/energy">www.ti.com/energy</a>
Industrial	<a href="http://www.ti.com/industrial">www.ti.com/industrial</a>
Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
Space, Avionics and Defense	<a href="http://www.ti.com/space-avionics-defense">www.ti.com/space-avionics-defense</a>
Video and Imaging	<a href="http://www.ti.com/video">www.ti.com/video</a>

### TI E2E Community

[e2e.ti.com](http://e2e.ti.com)